NSN 5961-01-003-4154

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-003-4154 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Height:** 0.450 inches **Overall Width:** 0.875 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 10.00 amperes all primaries **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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